

MC14518B, MC14520B

Dual Up Counters

The MC14518B dual BCD counter and the MC14520B dual binary counter are constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. Each consists of two identical, independent, internally synchronous 4-stage counters. The counter stages are type D flip-flops, with interchangeable Clock and Enable lines for incrementing on either the positive-going or negative-going transition as required when cascading multiple stages. Each counter can be cleared by applying a high level on the Reset line. In addition, the MC14518B will count out of all undefined states within two clock periods. These complementary MOS up counters find primary use in multi-stage synchronous or ripple counting applications requiring low power dissipation and/or high noise immunity.

Features

- Diode Protection on All Inputs
- Supply Voltage Range = 3.0 Vdc to 18 Vdc
- Internally Synchronous for High Internal and External Speeds
- Logic Edge-Clocked Design — Incremented on Positive Transition of Clock or Negative Transition on Enable
- Capable of Driving Two Low-power TTL Loads or One Low-power Schottky TTL Load Over the Rated Temperature Range
- Pb-Free Packages are Available*

MAXIMUM RATINGS (Voltages Referenced to V_{SS}) (Note 1.)

| Symbol | Parameter | Value | Unit |
|-------------------|---|------------------------|-------------|
| V_{DD} | DC Supply Voltage Range | -0.5 to +18.0 | V |
| V_{in}, V_{out} | Input or Output Voltage Range (DC or Transient) | -0.5 to $V_{DD} + 0.5$ | V |
| I_{in}, I_{out} | Input or Output Current (DC or Transient) per Pin | ± 10 | mA |
| P_D | Power Dissipation, per Package (Note 2.) | 500 | mW |
| T_A | Operating Temperature Range | -55 to +125 | $^{\circ}C$ |
| T_{stg} | Storage Temperature Range | -65 to +150 | $^{\circ}C$ |
| T_L | Lead Temperature (8-Second Soldering) | 260 | $^{\circ}C$ |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Maximum Ratings are those values beyond which damage to the device may occur.

2. Temperature Derating:

Plastic "P and D/DW" Packages: -7.0 mW/ $^{\circ}C$ From 65 $^{\circ}C$ To 125 $^{\circ}C$

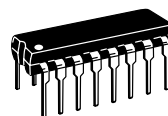
This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.

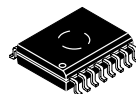
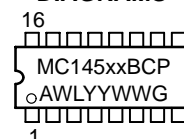


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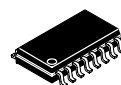
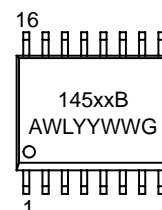
MARKING DIAGRAMS



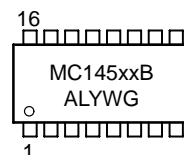
PDIP-16
P SUFFIX
CASE 648



SOIC-16
DW SUFFIX
CASE 751G



SOEIAJ-16
F SUFFIX
CASE 966



xx = 18 or 20
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Indicator

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

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ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

| Characteristic | Symbol | V _{DD} Vdc | - 55°C | | 25°C | | | 125°C | | Unit |
|--|------------------------------|------------------------|---|-------|-------|---------------------|-------|-------|-------|------|
| | | | Min | Max | Min | Typ ^(3.) | Max | Min | Max | |
| Output Voltage V _{in} = V _{DD} or 0 V _{in} = 0 or V _{DD} | "0" Level V _{OL} | 5.0 | — | 0.05 | — | 0 | 0.05 | — | 0.05 | Vdc |
| | | 10 | — | 0.05 | — | 0 | 0.05 | — | 0.05 | |
| | | 15 | — | 0.05 | — | 0 | 0.05 | — | 0.05 | |
| | "1" Level V _{OH} | 5.0 | 4.95 | — | 4.95 | 5.0 | — | 4.95 | — | |
| | | 10 | 9.95 | — | 9.95 | 10 | — | 9.95 | — | |
| | | 15 | 14.95 | — | 14.95 | 15 | — | 14.95 | — | |
| Input Voltage (V _O = 4.5 or 0.5 Vdc) (V _O = 9.0 or 1.0 Vdc) (V _O = 13.5 or 1.5 Vdc) (V _O = 0.5 or 4.5 Vdc) (V _O = 1.0 or 9.0 Vdc) (V _O = 1.5 or 13.5 Vdc) | "0" Level V _{IL} | 5.0 | — | 1.5 | — | 2.25 | 1.5 | — | 1.5 | Vdc |
| | | 10 | — | 3.0 | — | 4.50 | 3.0 | — | 3.0 | |
| | | 15 | — | 4.0 | — | 6.75 | 4.0 | — | 4.0 | |
| | "1" Level V _{IH} | 5.0 | 3.5 | — | 3.5 | 2.75 | — | 3.5 | — | |
| | | 10 | 7.0 | — | 7.0 | 5.50 | — | 7.0 | — | |
| | | 15 | 11 | — | 11 | 8.25 | — | 11 | — | |
| Output Drive Current (V _{OH} = 2.5 Vdc) (V _{OH} = 4.6 Vdc) (V _{OH} = 9.5 Vdc) (V _{OH} = 13.5 Vdc) (V _{OL} = 0.4 Vdc) (V _{OL} = 0.5 Vdc) (V _{OL} = 1.5 Vdc) | Source I _{OH} | 5.0 | -3.0 | — | -2.4 | -4.2 | — | -1.7 | — | mAdc |
| | | 5.0 | -0.64 | — | -0.51 | -0.88 | — | -0.36 | — | |
| | | 10 | -1.6 | — | -1.3 | -2.25 | — | -0.9 | — | |
| | | 15 | -4.2 | — | -3.4 | -8.8 | — | -2.4 | — | |
| | Sink I _{OL} | 5.0 | 0.64 | — | 0.51 | 0.88 | — | 0.36 | — | |
| | | 10 | 1.6 | — | 1.3 | 2.25 | — | 0.9 | — | |
| 15 | 4.2 | — | 3.4 | 8.8 | — | 2.4 | — | — | | |
| Input Current | I _{in} | 15 | — | ± 0.1 | — | ± 0.00001 | ± 0.1 | — | ± 1.0 | μAdc |
| Input Capacitance (V _{in} = 0) | C _{in} | — | — | — | — | 5.0 | 7.5 | — | — | pF |
| Quiescent Current (Per Package) | I _{DD} | 5.0 | — | 5.0 | — | 0.005 | 5.0 | — | 150 | μAdc |
| | | 10 | — | 10 | — | 0.010 | 10 | — | 300 | |
| | | 15 | — | 20 | — | 0.015 | 20 | — | 600 | |
| Total Supply Current ^(4.) ^(5.) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching) | I _T | 5.0 | I _T = (0.6 μA/kHz) f + I _{DD} | | | | | | | μAdc |
| | | 10 | I _T = (1.2 μA/kHz) f + I _{DD} | | | | | | | |
| | | 15 | I _T = (1.7 μA/kHz) f + I _{DD} | | | | | | | |

3. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

4. The formulas given are for the typical characteristics only at 25°C.

5. To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) Vfk$$

where: I_T is in μA (per package), C_L in pF, V = (V_{DD} - V_{SS}) in volts, f in kHz is input frequency, and k = 0.002.

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SWITCHING CHARACTERISTICS (6.) ($C_L = 50 \text{ pF}$, $T_A = 25^\circ\text{C}$)

| Characteristic | Symbol | V_{DD} | All Types | | | Unit |
|--|---|--|--------------------------------|--|--|---------------|
| | | | Min | Typ (7.) | Max | |
| Output Rise and Fall Time t_{TLH} , $t_{THL} = (1.5 \text{ ns/pF}) C_L + 25 \text{ ns}$ t_{TLH} , $t_{THL} = (0.75 \text{ ns/pF}) C_L + 12.5 \text{ ns}$ t_{TLH} , $t_{THL} = (0.55 \text{ ns/pF}) C_L + 9.5 \text{ ns}$ | t_{TLH} , t_{THL} | 5.0 10 15 | — — — | 100 50 40 | 200 100 80 | ns |
| Propagation Delay Time Clock to Q/Enable to Q t_{PLH} , $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 215 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 97 \text{ ns}$ t_{PLH} , $t_{PHL} = (0.5 \text{ ns/pF}) C_L + 75 \text{ ns}$ Reset to Q $t_{PHL} = (1.7 \text{ ns/pF}) C_L + 265 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 117 \text{ ns}$ $t_{PHL} = (0.66 \text{ ns/pF}) C_L + 95 \text{ ns}$ | t_{PLH} , t_{PHL} t_{PHL} | 5.0 10 15 5.0 10 15 | — — — — — — | 280 115 80 330 130 90 | 560 230 160 650 230 170 | ns |
| Clock Pulse Width | $t_{w(H)}$ $t_{w(L)}$ | 5.0 10 15 | 200 100 70 | 100 50 35 | — — — | ns |
| Clock Pulse Frequency | f_{cl} | 5.0 10 15 | — — — | 2.5 6.0 8.0 | 1.5 3.0 4.0 | MHz |
| Clock or Enable Rise and Fall Time | t_{THL} , t_{TLH} | 5.0 10 15 | — — — | — — — | 15 5 4 | μs |
| Enable Pulse Width | $t_{WH(E)}$ | 5.0 10 15 | 440 200 140 | 220 100 70 | — — — | ns |
| Reset Pulse Width | $t_{WH(R)}$ | 5.0 10 15 | 280 120 90 | 125 55 40 | — — — | ns |
| Reset Removal Time | t_{rem} | 5.0 10 15 | -5 15 20 | -45 -15 -5 | — — — | ns |

6. The formulas given are for the typical characteristics only at 25°C .

7. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

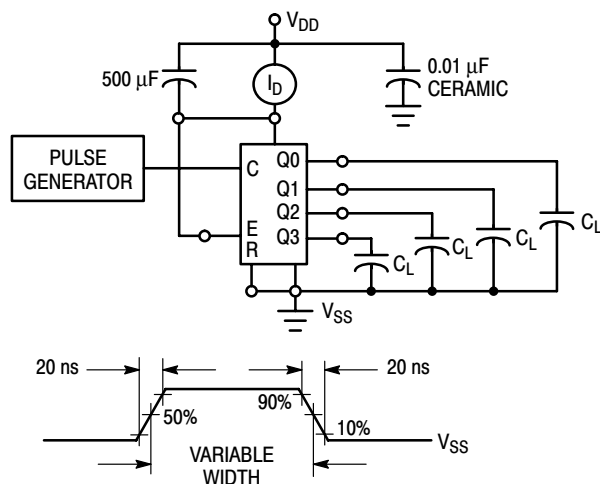


Figure 1. Power Dissipation Test Circuit and Waveform

MC14518B, MC14520B

ORDERING INFORMATION

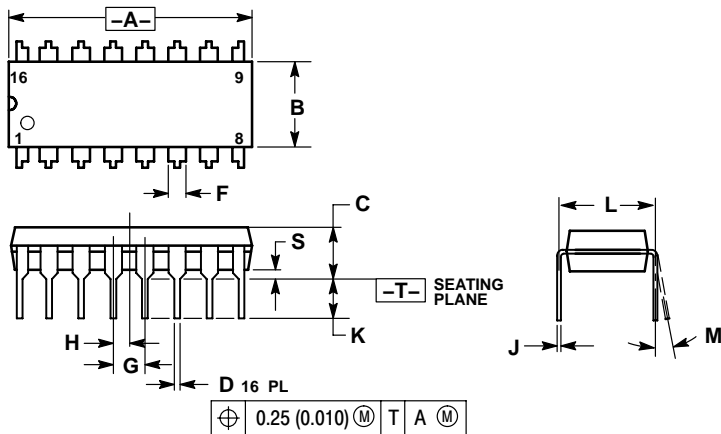
| Device | Package | Shipping† |
|---------------|------------------------|--------------------------|
| MC14518BCP | PDIP-16 | 500 Units / Rail |
| MC14518BCPG | PDIP-16 (Pb-Free) | 500 Units / Rail |
| MC14518BDW | SOIC-16 | 47 Units / Rail |
| MC14518BDWG | SOIC-16 (Pb-Free) | 47 Units / Rail |
| MC14518BDWR2 | SOIC-16 | 1000 Units / Tape & Reel |
| MC14518BDWR2G | SOIC-16 (Pb-Free) | 1000 Units / Tape & Reel |
| MC14518BFEL | SOEIAJ-16 | 2000 Units / Tape & Reel |
| MC14518BFELG | SOEIAJ-16 (Pb-Free) | 2000 Units / Tape & Reel |
| MC14520BCP | PDIP-16 | 500 Units / Rail |
| MC14520BCPG | PDIP-16 (Pb-Free) | 500 Units / Rail |
| MC14520BDW | SOIC-16 | 47 Units / Rail |
| MC14520BDWG | SOIC-16 (Pb-Free) | 47 Units / Rail |
| MC14520BDWR2 | SOIC-16 | 1000 Units / Tape & Reel |
| MC14520BDWR2G | SOIC-16 (Pb-Free) | 1000 Units / Tape & Reel |
| MC14520BFEL | SOEIAJ-16 | 2000 Units / Tape & Reel |
| MC14520BFELG | SOEIAJ-16 (Pb-Free) | 2000 Units / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PACKAGE DIMENSIONS

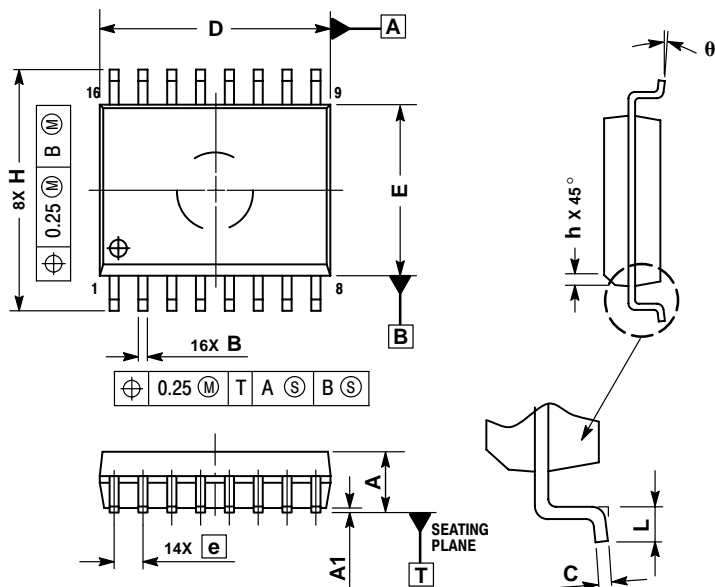
PDIP-16 P SUFFIX PLASTIC DIP PACKAGE CASE 648-08 ISSUE T



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

| DIM | INCHES | | MILLIMETERS | |
|-----|-----------|-------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.740 | 0.770 | 18.80 | 19.55 |
| B | 0.250 | 0.270 | 6.35 | 6.85 |
| C | 0.145 | 0.175 | 3.69 | 4.44 |
| D | 0.015 | 0.021 | 0.39 | 0.53 |
| F | 0.040 | 0.70 | 1.02 | 1.77 |
| G | 0.100 BSC | | 2.54 BSC | |
| H | 0.050 BSC | | 1.27 BSC | |
| J | 0.008 | 0.015 | 0.21 | 0.38 |
| K | 0.110 | 0.130 | 2.80 | 3.30 |
| L | 0.295 | 0.305 | 7.50 | 7.74 |
| M | 0° | 10° | 0° | 10° |
| S | 0.020 | 0.040 | 0.51 | 1.01 |

SOIC-16 DW SUFFIX PLASTIC SOIC PACKAGE CASE 751G-03 ISSUE C



- NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF THE B DIMENSION AT MAXIMUM MATERIAL CONDITION.

| DIM | MILLIMETERS | |
|----------|-------------|-------|
| | MIN | MAX |
| A | 2.35 | 2.65 |
| A1 | 0.10 | 0.25 |
| B | 0.35 | 0.49 |
| C | 0.23 | 0.32 |
| D | 10.15 | 10.45 |
| E | 7.40 | 7.60 |
| e | 1.27 BSC | |
| H | 10.05 | 10.55 |
| h | 0.25 | 0.75 |
| L | 0.50 | 0.90 |
| θ | 0° | 7° |